

P-Channel 30-V (D-S) MOSFET

Description

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low rDS(on) and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

Features

- Low rDS(on) trench technology
- · Low thermal impedance
- · Fast switching speed
- · RoHS compliant package

Typical Applications:

- · White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

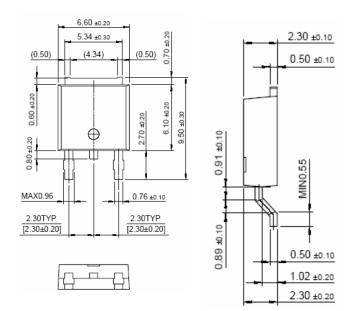
Packing & Order Information

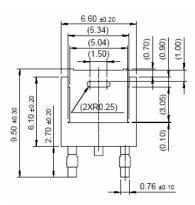
Part No./ T ÷ 2,500/Tape&Reel Part No./ R ÷ 80/Tube , 4,000/Box



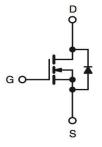


Graphic symbol





Graphic symbol



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings (T _A =25°C unless otherwise specified)					
Symbol	Parameter	Value	Unit		
V _{DS}	Drain-Source Voltage	30	V		
V _{GS}	Gate-Source Voltage	±20	V		
I _D	Continuous Drain Current ^a (T _A =25°C)	75	A		
I _{DM}	Pulsed Drain Current ^b	300	A		
ls	Continuous Source Current (Diode Conduction) ^a	30	A		



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Absolute Maximum Ratings (T _A =25°C unless otherwise specified)					
Symbol	Parameter	Unit			
P _D	Power Dissipation ^a ($T_A = 25^{\circ}C$)	50	W		
T _J /T _{STG}	Operating Junction and Storage Temperature	-55 to +175	°C		
R _{θJA}	Maximum Junction-to-Ambient ^a (t <= 10 sec)	40	°C/W		
$R_{ extsf{ heta}JC}$	Maximum Junction-to-Ambient ^a (Steady-State)	3	0/11		

Notes

a. Surface Mounted on 1" x 1" FR4 Board.

b. Pulse width limited by maximum junction temperature

Static						
Symbol	Parameter	Test Conditions	Min	Тур.	Max.	Units
V _{GS(th)}	Gate-Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = -250 \mu A$	1			V
I _{GSS}	Gate-Body Leakage	$V_{DS} = 0 V$, $V_{GS} = \pm 20 V$			±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24 V$, $V_{GS} = 0 V$ $V_{DS} = 24 V$, $V_{GS} = 0 V$, $T_{J} = 55^{\circ}C$			1 25	uA
I _{D(on)}	On-State Drain Current	$V_{DS} = 5 V, V_{Gs} = 10 V$	120			А
r DS(on)	Drain-Source On-Resistance	$V_{DS} = 10 \text{ V}, I_D = 20 \text{ A}$ $V_{GS} = 4.5 \text{ V}, I_D = 18 \text{ A}$			6 8	mΩ
g _{fs}	Forward Tranconductance	V _{GS} = 15 V, I _D = 20 A		20		S
V_{SD}	Diode Forward Voltage	$I_{\rm S}$ = 15 A , $V_{\rm GS}$ = 0 V		0.84		V

Dynamic						
Symbol	Parameter	Test Conditions	Min	Тур.	Max.	Units
Q_{g}	Total Gate Charge	$V_{DS} = 15 \text{ V}$, $I_D = 20 \text{ A}$, $V_{GS} = 4.5 \text{ V}$		20		nC
Q_{gs}	Gate-Source Charge			7.3		nC
Q_{gd}	Gate-Drain Charge			11		nC
t _{d(on)}	Turn-On Delay Time	$I_{D} = 20 \text{ A}, \text{ R}_{L} = 0.8 \Omega,$ $V_{GEN} = 10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$ $V_{DS} = 15 \text{ V}$		10		ns
t _r	Rise Time			13		ns
t _{d(off)}	Turn-Off Delay Time			51		ns
tf	Fall Time			21		ns
C _{ISS}	Input Capacitance	V _{DS} = 15 V f = 1 MHz ,V _{GS} = 0 V		1785		pF
C _{OSS}	Output Capacitance			323		pF
C _{RSS}	Reverse Transfer Capacitance			285		pF

Notes

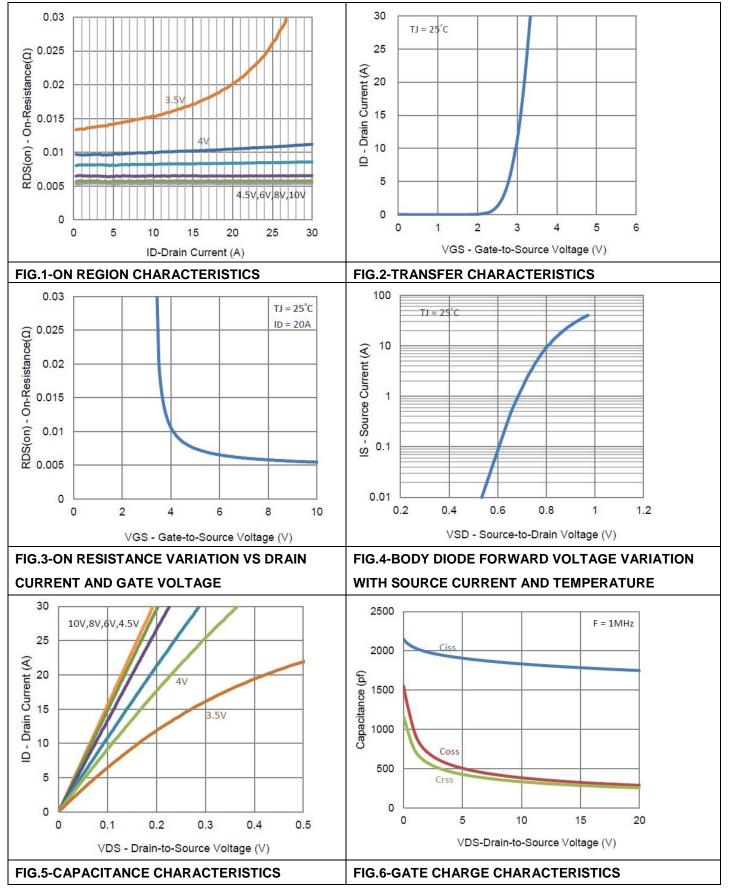
a. Pulse test: PW <= 300us duty cycle <= 2%.

b. Guaranteed by design, not subject to production testing.



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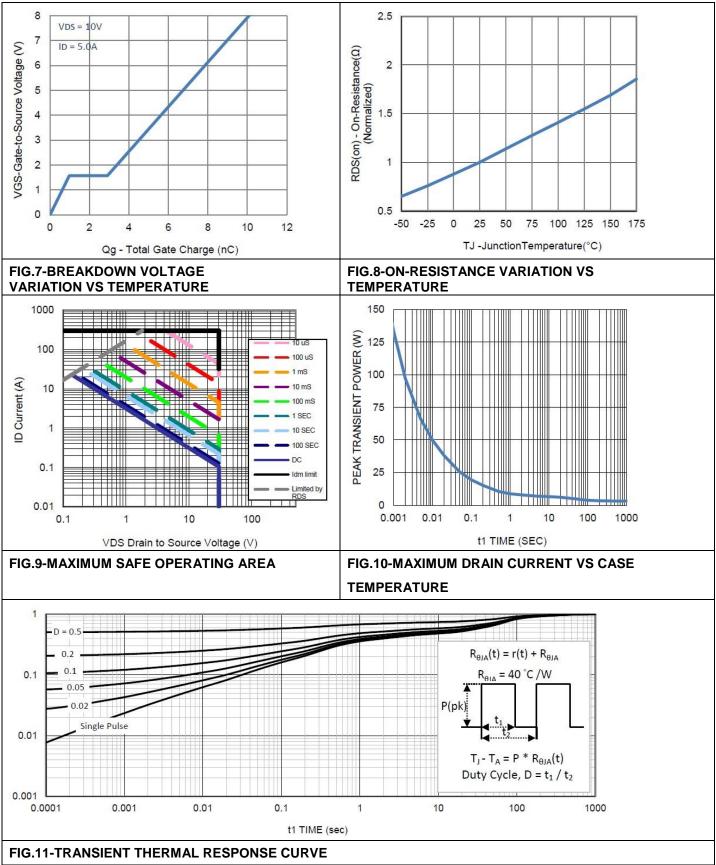
Typical Electrical Characteristics





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